

# Unisys

DATE: February 18, 1999  
TO: J. Dafnis/303  
FROM: K. Sahu/S. Kniffin/300.1  
SUBJECT: Radiation Report on **OP07 (Analog Devices) (LDC 9724A)**  
PROJECT: GOES (ITT)

PPM-99-016

cc: R. Ross/562, R. Reed/562, D. Maus/ITT, L. Deemer/300.1, A. Sharma/562, OFA Library/300.1

A radiation evaluation was performed on **OP07 Low Power, High Precision Operational Amplifier (Analog Devices)** to determine the total dose tolerance of these parts. This testing was a follow-up to the earlier testing of OP-07 LDC9724A. The earlier testing indicated some outlier parts with very high VOS degradation. (Refer to Appendix 1 in this report, PPM-99-001 and PPM-98-011.) The total dose testing was performed using a Co<sup>60</sup> gamma ray source. During the radiation testing, eighteen parts were irradiated under bias (see Figure 1 for bias configuration) and two parts were used as control samples. The total dose radiation levels were 5.0, 10.0, 20.0, 30.0, and 40.0kRads.<sup>1</sup> The dose rate was 0.049 kRads/hour (0.014 Rads/s). See Table II for the radiation schedule and effective dose rate calculation. After the 40.0kRad irradiation, the parts were annealed at 25°C for 24 and 168 hours under bias and 336 hours without bias.<sup>2</sup> After each radiation exposure and annealing treatment, parts were electrically tested according to the test conditions and the specification limits<sup>3</sup> listed in Table III. An executive summary of the test results is provided below in bold, followed by a detailed summary of the test results after each radiation level and annealing step. For detailed information, refer to Tables I through IV and Figures 1 and 2.

**Most parts showed some degradation in VOS beginning at 20kRads, however, no signs of excessive degradation were seen and there was no VOS outlier problem throughout this testing (See Appendix 1). All parts showed marginal degradation in P\_IIB and N\_IIB from 10 to 40kRads. All parts showed some degradation in N\_AOL\_2k from 20 to 40kRads. Most parts showed some degradation in CMRR from 30 to 40kRads. Some increase was noted in VOS after annealing the parts under bias at 25°C for 24 and 168 hours. However, the readings decreased after continued unbiased annealing. (See Figure 2.)**

Initial electrical measurements were made on 20 samples. Eighteen samples (SN's 398, 399, 409, 410, 694, 710, 732, 751, 763, 764, 776, 777, 796, 798, 804, 805, 827, and 828) were used as radiation samples while SN's 387 and 388 were used as control samples. All parts passed all tests during initial electrical measurements.

After the 5.0kRad irradiation, one part fell below the specification limit of -25µV for VOS with a reading of -28µV. **All parts passed all other tests.**

After the 10.0kRad irradiation, all parts were within the specification limits for Vos. Thirteen parts exceeded the specification limit of 2.0nA for P\_IIB with readings in the range of 2.1 to 3.3nA. Eight parts exceeded the specification limit of 2.0nA for and N\_IIB with readings in the range of 2.1 to 3.0nA. **All parts passed all other tests.**

After the 20.0kRad irradiation, two parts exceeded the specification limit of 25µV for VOS with readings of 29.6 and 26.8µV. All parts exceeded the specification limit for P\_IIB and N\_IIB with readings in the range of 4.2 to 8.5nA for both. All parts fell below the specification limit of 300V/mV for N\_AOL\_2k with readings in the range of 243 to 286V/mV. **All parts passed all other tests.**

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<sup>1</sup> The term Rads, as used in this document, means Rads (silicon). All radiation levels cited are cumulative.

<sup>2</sup> The temperature 25°C as used in this document implies room temperature.

<sup>3</sup> These are manufacturer's pre-irradiation data specification limits. The manufacturer provided no post-irradiation limits at the time these tests were performed.

After the 30.0kRad irradiation, eight parts exceeded the specification limit for VOS with readings in the range of 25.7 to 45.7 $\mu$ V. All parts exceeded the specification limit for P\_IIB and N\_IIB with readings in the range of 7.2 to 11.7nA for both. Ten parts fell marginally below the specification limit of 110dB for CMRR with readings in the range of 109.8 to 107.9dB. All parts fell below the specification limit for N\_AOL\_2k with readings in the range of 218 to 253V/mV. **All parts passed all other tests.**

After the 40.0kRad irradiation, fourteen parts exceeded the specification limit for VOS with readings in the range of 25.1 to 58.9 $\mu$ V. All parts exceeded the specification limit for P\_IIB and N\_IIB with readings in the range of 10.2 to 15.5nA for both. Fifteen parts fell marginally below the specification limit of for CMRR with readings in the range of 108.9 to 105.8dB. One part fell marginally below the specification limit of 300V/mV for P\_AOL\_2k with a reading of 297V/mV. All parts fell below the specification limit for N\_AOL\_2k with readings in the range of 193 to 232V/mV. **All parts passed all other tests.**

After annealing the parts for 24 hours at 25°C, parts showed no significant change in any parameter.

After annealing the parts for 168 hours at 25°C, parts showed no significant recovery in any parameter. The parts did show a slight increase in VOS with 16 parts exceeding the specification limit with readings in the range of 33 to 305 $\mu$ V. On continued annealing for 336 hours unbiased at 25°C, the parts showed a decrease in VOS readings with readings in the range of 34 to 250 $\mu$ V.

Table IV provides a summary of the test results with the mean and standard deviation values for each parameter after each irradiation exposure and annealing step.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call us at (301) 731-8954.

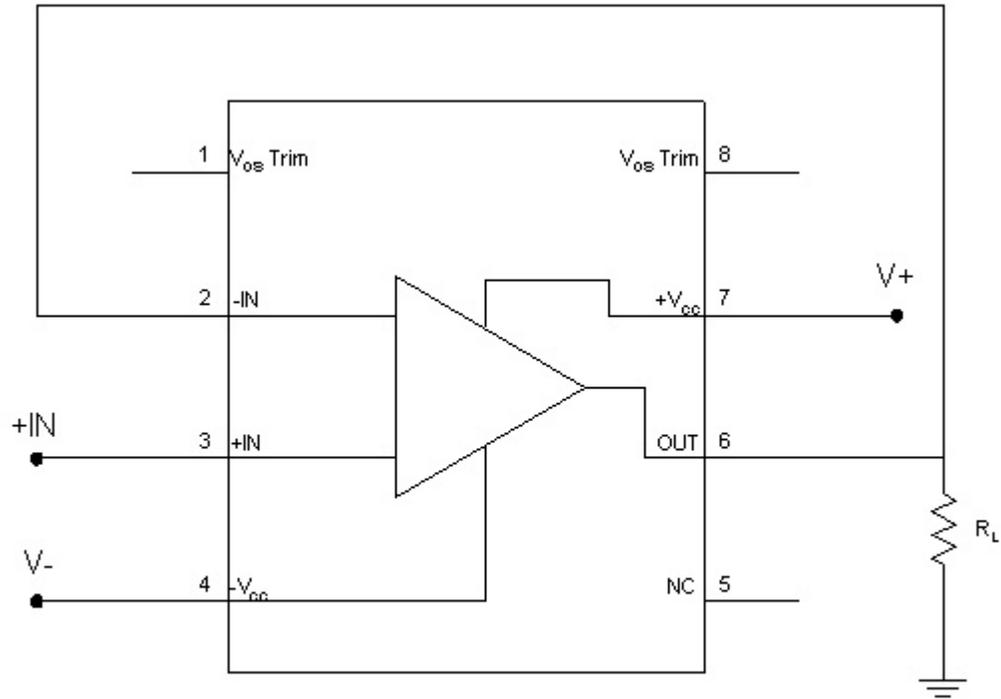
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Figure 1. Radiation Bias Circuit for OP07



Notes:

1.  $R_L = 402\Omega \pm 5\%$ ,  $\frac{1}{2}W$ .
2. +IN = 3.0V, V+ = +15V, V- = -15V.

TABLE I. Part Information

Generic Part Number:	OP07
GOES ITT Part Number	OP07
Charge Number:	M90406
Manufacturer:	Analog Devices
Lot Date Code (LDC):	9724A
Quantity Tested:	20
Serial Number of Control Samples:	387, 388
Serial Numbers of Radiation Samples:	398, 399, 409, 410, 694, 710, 732, 751, 763, 764, 776, 777, 796, 798, 804, 805, 827, and 828
Part Function:	Low Power, High Precision Operational Amplifier
Part Technology:	Bipolar
Package Style:	8-Pin DIP
Test Equipment:	A540
Test Engineer:	S. Archer-Davies

- The manufacturer for this part guaranteed no radiation tolerance/hardness.

TABLE II. Radiation Schedule for OP07

EVENT .....	DATE
1) INITIAL ELECTRICAL MEASUREMENTS .....	12/22/98
2) 5.0 KRAD IRRADIATION (0.031 KRADS/HOUR).....	12/23/98
POST-5.0 KRAD ELECTRICAL MEASUREMENT .....	12/30/98
3) 10.0 KRAD IRRADIATION (0.031 KRADS/HOUR).....	12/30/98
POST-10.0 KRAD ELECTRICAL MEASUREMENT .....	01/06/99
4) 20.0 KRAD IRRADIATION (0.062 KRADS/HOUR).....	01/06/99
POST-20.0 KRAD ELECTRICAL MEASUREMENT .....	01/13/99
5) 30.0 KRAD IRRADIATION (0.062 KRADS/HOUR).....	01/13/99
POST-30.0 KRAD ELECTRICAL MEASUREMENT .....	01/19/99
6) 40.0 KRAD IRRADIATION (0.062 KRADS/HOUR).....	01/19/99
POST-40.0 KRAD ELECTRICAL MEASUREMENT .....	01/26/99
7) 24 HOUR ANNEALING @25°C.....	01/26/99
POST-24 HOUR ANNEAL ELECTRICAL MEASUREMENT .....	01/27/99
8) 168 HOUR ANNEALING @25°C.....	01/26/99
POST-168 HOUR ANNEAL ELECTRICAL MEASUREMENT .....	02/03/99
9) 336 HOUR ANNEALING UNBIASED @25°C.....	02/03/99
POST-336 HOUR ANNEAL ELECTRICAL MEASUREMENT .....	02/17/99

Effective Dose Rate = 40,000 RADS/34 DAYS=49.0 RADS/HOUR=0.014 RADS/SEC

PARTS WERE IRRADIATED AND ANNEALED UNDER BIAS, SEE FIGURE 1.

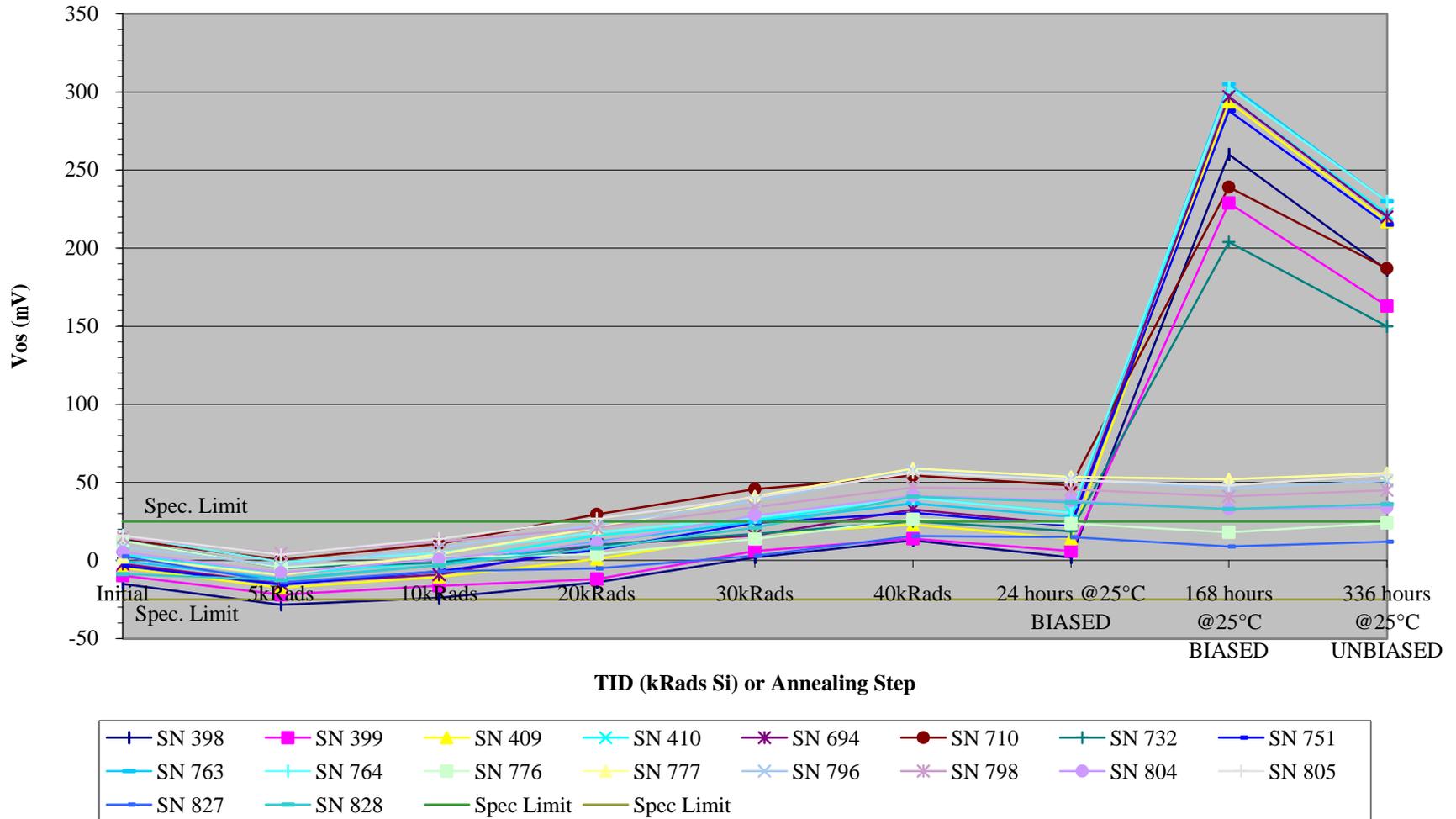
Table III. Electrical Characteristics of OP07 /1

Test #	Parameter	Units	Test Conditions	Spec. min	Lim. max
1	+Icc	mA	+V <sub>S</sub> = +15V, V <sub>O</sub> = 0V	0.0	4.0
2	-Icc	mA	-V <sub>S</sub> = -15V, V <sub>O</sub> = 0V	-4.0	0.0
3	Power_Diss	mW	V <sub>CC</sub> = ±15V, V <sub>O</sub> = 0V		120
4	VOS	μV	V <sub>CM</sub> = 0V	-25	25
5	P_IIB	nA	V <sub>CM</sub> = 0V	-2.0	2.0
6	N_IIB	nA	V <sub>CM</sub> = 0V	-2.0	2.0
7	IIOS	nA	V <sub>CM</sub> = 0V	-2.0	2.0
8	CMRR	dB	V <sub>CM</sub> = ±13V	110	
9	PSRR	dB	±V <sub>CC</sub> = ±3V to ±18V, ∓V <sub>CC</sub> = ∓15V	100	
10	P_VOUT_10k	V	R <sub>L</sub> = 10kΩ	12.5	
11	N_VOUT_10k	V	R <sub>L</sub> = 10kΩ		-12.5
12	P_VOUT_2k	V	R <sub>L</sub> = 2kΩ	12.0	
13	N_VOUT_2k	V	R <sub>L</sub> = 2kΩ		-12.0
14	P_AOL_2k	V/mV	R <sub>L</sub> = 2kΩ, V <sub>O</sub> = +10V	300	
15	N_AOL_2k	V/mV	R <sub>L</sub> = 2kΩ, V <sub>O</sub> = -10V	300	
16	P_AOL_600	V/mV	R <sub>L</sub> = 600Ω, V <sub>O</sub> = +10V	150	
17	N_AOL_600	V/mV	R <sub>L</sub> = 600Ω, V <sub>O</sub> = -10V	150	
18	Slew Rate	V/μs	C <sub>L</sub> = 50pF, R <sub>L</sub> = 2kΩ	0.100	

Notes:

1/ These are the manufacturer's non-irradiated data sheet specification limits. The manufacturer provided no post-irradiation limits at the time the tests were performed.

**Figure 2: Vos vs TID for OP-07 at 0.004R/s**  
 LDC 9724A, Radiation sample Size = 18  
**Outliers Seen: None**



## Appendix 1

The following is the transcript of the email to Jim Dafnis, Code 303, describing the final results and recommendation for OP07 LDC9724A.

Jim,

We're summarizing below the TID radiation testing performed on OP-07 LDC9724A for the GOES project to determine the suitability of these parts from a TID aspect. The recommendation that you asked for this morning on these parts is provided at the bottom.

Kusum and Scott

### **Background:**

We tested 4 parts of LDC 9724A in Nov 98 at 0.14R/s. One part in this lot showed significant degradation in the Vos test parameter at 40kRads. The readings were 3148 $\mu$ V with a spec limit of 25 $\mu$ V. The other three parts were within +/-10% of the spec limit at 40kRads.

We also tested 4 parts of this LDC at 0.58R/s. At 50kRads, the parts showed significant degradation in Vos. The mean was 370 $\mu$ V but there was no outlier. Note that the rate of degradation was dramatically higher than at the lower dose rate of 0.14R/s. Also note that the parts showed significant recovery on annealing at room temp after the final exposure. See PPM-99-001 for more details.

We had also tested 8 parts of LDC 9723B in May 98 at 0.33R/s. One part showed significant degradation in the Vos test parameter with a reading of 3249 $\mu$ V at 40kRads. The readings for the other 7 parts were within +/-60 $\mu$ V with a spec limit of 25 $\mu$ V. See PPM-98-011 for more details.

The results above raised the issue as to how significant the outlier problem was for the LDC9724A parts, of which many have been used in the GOES project. There was also a question regarding whether the outlier issue would couple with the Extremely Low Dose Rate Effect (ELDR) and make the problem worse in the space environment where the dose rate may be smaller by a factor of 10-100.

A test plan was designed to test a larger sample size of OP-07 parts from LDC9724A at a dose rate of about 0.004R/s. It was determined that these parts would be tested to 40kRads only, to see how significant the outlier problem is in this test group at the lower dose rate. The 40kRad level was chosen because the project determined that the radiation exposure at the part level was going to be less than 17kRads thereby giving an RDM of >2 at 40kRads. Although a RDM of 5 would have been better, that would have taken too long to resolve this issue at this dose rate.

### **New/Recent Test Results:**

The testing of the 18 parts up to 40kRads was finished 2 days ago and the Vos results are summarized below.

All parts stayed within the specification limit of 25 $\mu$ V up to 10kRads. At 20kRads, all parts except 2 stayed within the specification limit. Only 2 parts marginally exceeded the limit with readings of 29.6 and 26.8 $\mu$ V.

After 30kRads, 8 parts exceeded (10 parts stayed within) the Vos spec limit with readings in the range of 25.7 to 45.7 $\mu$ V.

After 40kRads, 13 parts exceeded (5 stayed within) the Vos spec limit with readings in the range of 25 to 59 $\mu$ V.

See the attached figure for a graphical representation of the Vos degradation with increasing TID exposure up to 40kRads.

The new test data on a sample size of 18 at lower dose rate (0.004R/s) does not indicate any outlier problem as related to the Vos parameter up to 40kRads. It should be noted that in general, the OP-07 parts showed higher degradation at the higher dose rate of 0.58R/s. The dose rate of the space environment is much less than the dose rates at which the outlier problem was observed in our testing. Even if there is an outlier, it probably will not show as much degradation in space as it did in our testing at 0.14R/s.

(Please note that a number of other parameters such as P\_IIB, N\_IIB, CMRR, etc. showed marginal degradation from the specification limit. Those results will be included in the final report, but do not impact the primary issue of Vos outliers.)

**Recommendation:**

**The lack of the outlier problem as well as any significant degradation in Vos up to 40kRads at the low dose rate of 0.004R/s in a sample size of 18, greatly reduces the risk associated with the use of these parts in the GOES project where the expected exposure on the parts is less than 17kRads. However, the project should determine that in the event of an outlier, the resulting Vos will not cause a critical functional failure in its intended application.**